A Table-Top Experimental setup Testing Silicon Sensors

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Motivation

- Advantages of Test Beams:
- High-energy particles with low multiple scattering provide the necessary precision for detailed spatial mapping.
- Challenges with Test Beams:
- Require time slots and resources at dedicated facilities (e.g., CERN SPS, DESY).
- Complex setup with specialized tracking telescopes like the EUDET telescope with MIMOSA planes.
- Our Purpose
- A discussion on beta particle calibrating the silicon sensors



Figure 3: Detector telescope used with a pion beam. The relative positions of the different detectors are reported (in mm) with respect to the X_1 detector, used as the origin.

Cosmic Ray Muons?

- Advantage:
 - Low multiple scattering
- Rate of Cosmic Rays:
 - Muons arrive at ~1 muon/min/cm².
- Time Requirement:
 - For a 1mm x 1mm DUT with 5μm x 5μm bins and ~100 events per bin
 - Need ~100 years by assuming 100% muon detections efficiency for calibration



A Table-Top Experiment

- **High-Energy Beta Particles**: Ensures effective penetration and minimal scattering.
- **Detector Configuration**: DUT sandwiched between detectors, with a pixel detector as the final layer.
- **Calibration Goals**: Achieve both time and spatial calibration.
- Key Considerations:
 - Source Selection
 - Geometry Placement
 - Multiple-Scattering Analysis



Source Consideration

- Source Requirements
- **High-Energy Particles:** Ensures effective penetration and minimal scattering.
- **Stability During Testing:** Long enough half-life to maintain consistent emission over the testing period.
- Phosphorus-32P
 - Maximum Energy: 1.71 MeV
 - Half-Life: ~14.3 days
- 106Ru and 106Rh
 - Maximum Energy: 3.54 MeV (from 106^{106}106Rh decay)
 - Half-Life: 106Ru ~373.6 days; 106Rh,~30 seconds.
- Chosen Source: 90Sr with a beta spectrum up to 2.28 MeV



Particle Selection - Electron Monochromator



Momentum Selection performance

- **High-Energy Selection**: Reduce multiplescattering, increase the selection precision.
- Momentum Precision: Generally better than 10%, reaching approximately 5% for momenta above 1.5 MeV/c. (Source: S. Arfaoui, C. Joram, C. Casella, 2015)

High-Activity Source Requirement

• **Trigger Rate**: Typical trigger rate of around 10 Hz, achieved with thick, square scintillating fibers positioned approximately 1 cm from the exit slit. (*Source: S. Arfaoui, C. Joram, C. Casella, 2015*)

Geometry Placement



Geometry placement

• details:

Scanning Tracking Technique





General Idea:

Create a detailed spatial map of the sensor's response

High-Activity Source Requirement

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Initial Investigation

- Evaluate the feasibility of the proposed setup using a simplified particle source model.
- By utilizing Geant4 simulations to optimize the geometry for a configuration that minimizes scattering effects, ensuring accurate trajectory measurements.
- Key Parameter Δθ: Define Δθ as the angular deviation of a particle moving through each detection sensor.

Geant4 Simulation - Geometry



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Geant4 Simulation - Physics List

- RegisterPhysics(new **G4DecayPhysics()**);
- RegisterPhysics(new G4RadioactiveDecayPhysics());
 - To generate decay process
- RegisterPhysics(new **G4EmStandardPhysics_option4()**);
 - Compared to G4EmStandardPhysics, option4 provides higher accuracy in Multiple Scattering simulation below ~100MeV (V. Ivanchenko, 2018)

Geant4 Simulation – Simulation Structure

• Some thing like this?



Geant4 Simulation – Material definition

- Silicon Sensors:
 - Assuming pure silicon crystal G4_Si
- Detector Holder Plate:
 - Woven Glass Fabric composition (15%):
 - Silicon (Si): ~33-35%; Oxygen (O): ~48-50%; Aluminum (Al): ~10-15%; Calcium (Ca): ~3-5%; Magnesium (Mg): ~1-2%
 - Ceramic filler (55%):
 - Oxygen (O): ~50-60%; Silicon (Si): ~20-30%; Aluminum (Al): ~5-15%; Calcium (Ca): ~1-5%; Magnesium (Mg): ~1-3%
 - Hydrocarbon Resin (30%):
 - Carbon (C): ~85-90%; Hydrogen (H): ~8-10%; Oxygen (O): Trace to 5%

Geant4 Simulation – Particle Gun and Tracking Actions

- Option 1 decay generator:
 - Create random number 0-1, randomly pick 90Sr and 90Y decay process, to get a mixture spectrum
 - Kill the electron tracks if the direction is out side the emiting angle, and kill all the non-electron tracks
 - 1 decay in each G4Event
- Option 2 Electron particle gun:
 - 2.2MeV electron particle gun, momentum alines on z direction
 - 1 electron generated in each G4Event
- Stop generating until 10^6 tracks are recorded

Primary Results – Total Angular deviation

AngleChange



Primary Results – Distribution

fX:fY



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